

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			100	V	
V _{GS}	Gate to Source Voltage			±20	V	
ID	Drain Current -Continuous	T _C = 25 °C		18		
	-Continuous	T _A = 25 °C	(Note 1a)	7	Α	
	-Pulsed			30		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	63	mJ	
P _D	Power Dissipation	Dissipation $T_{C} = 25 \text{ °C}$		41	w	
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	VV	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

R_{\thetaJC}	Thermal Resistance, Junction to Case	3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1a)	53	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC86102L	FDMC86102L	Power 33	13 "	12 mm	3000 units

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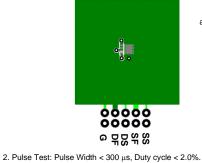
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	octeristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, V_{GS} = 0 \ V$	100			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		71		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			1	μA	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1	1.8	3	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 7 A		18.9	23		
		$V_{GS} = 4.5 \text{ V}, I_D = 5.5 \text{ A}$		24.9	34		
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 7 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$		31.9	39		
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 7 A$		26		S	
Dynamic C _{iss}	Characteristics Input Capacitance	N 50 Y Y 0 Y		999	1330	pF	
C _{oss}	Output Capacitance	V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz		178	240	pF	
C _{rss}	Reverse Transfer Capacitance			7.6	15	pF	
R _g	Gate Resistance			0.5		Ω	
Switching	Characteristics						
t _{d(on)}	Turn-On Delay Time			7.7	16	ns	
t _r	Rise Time	V _{DD} = 50 V, I _D = 7 A,		2.2	10	ns	
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		19	34	ns	
t _f	Fall Time			2.4	10	ns	
Q _{g(TOT)}	Total Gate Charge	$\frac{V_{GS} = 0 \text{ V to } 10 \text{ V}}{V_{GS} = 0 \text{ V to } 4.5 \text{ V}} V_{DD} = 50 \text{ V},$ $I_{D} = 7 \text{ A}$		15	22	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V$ $V_{DD} = 50 V,$		7.3	11	nC	
Q _{gs}	Total Gate Charge	$I_{\rm D} = 7$ A		2.7		nC	
Q _{gd}	Gate to Drain "Miller" Charge			2.3		nC	
Drain-Sou	urce Diode Characteristics						
	Source to Droip Diode, Forward Maltan	$V_{GS} = 0 V, I_S = 7 A$ (Note 2)		0.81	1.3	V	
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.74	1.2	v	
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Q_{rr} NOTES:

t_{rr}

1. $R_{0,LR}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{0,LC}$ is guaranteed by design while $R_{0,CA}$ is determined by the user's board design.

 $I_F = 7 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$



3. Starting T_J = 25 °C; N-ch: L = 1 mH, I_{AS} = 11.3 A, V_{DD} = 90 V, V_{GS} = 10 V.

Reverse Recovery Time

Reverse Recovery Charge

a) 53 °C/W when mounted on a 1 in²pad of 2 oz copper



b) 125 °C/W when mounted on a minimum pad of 2 oz copper

45

45

72

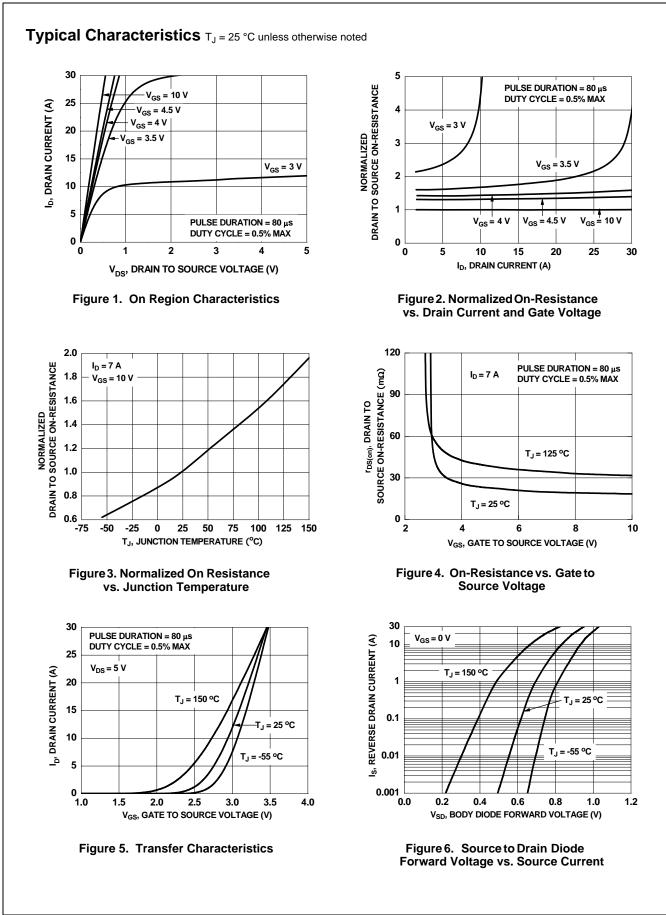
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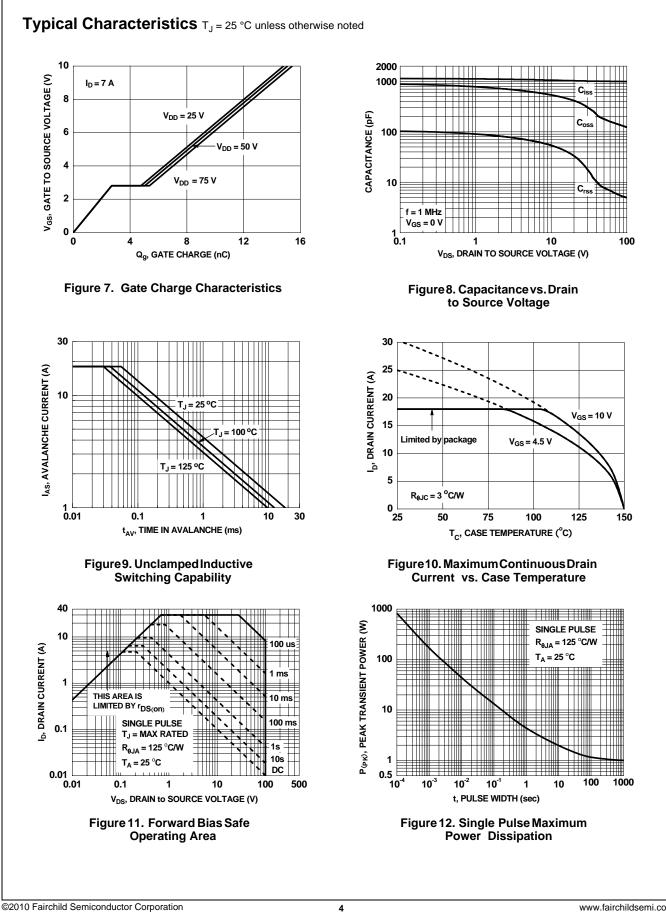
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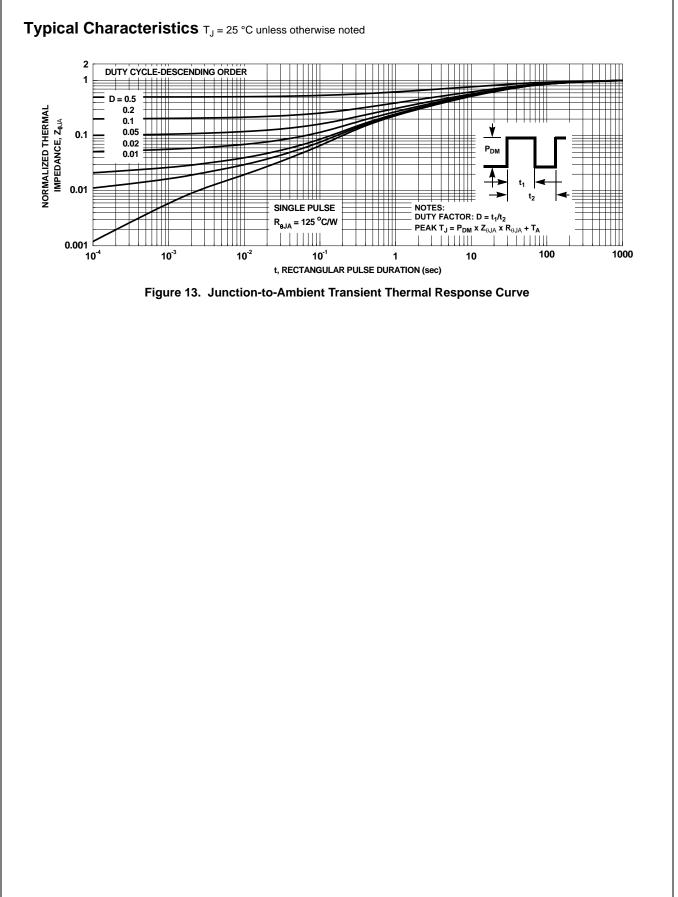
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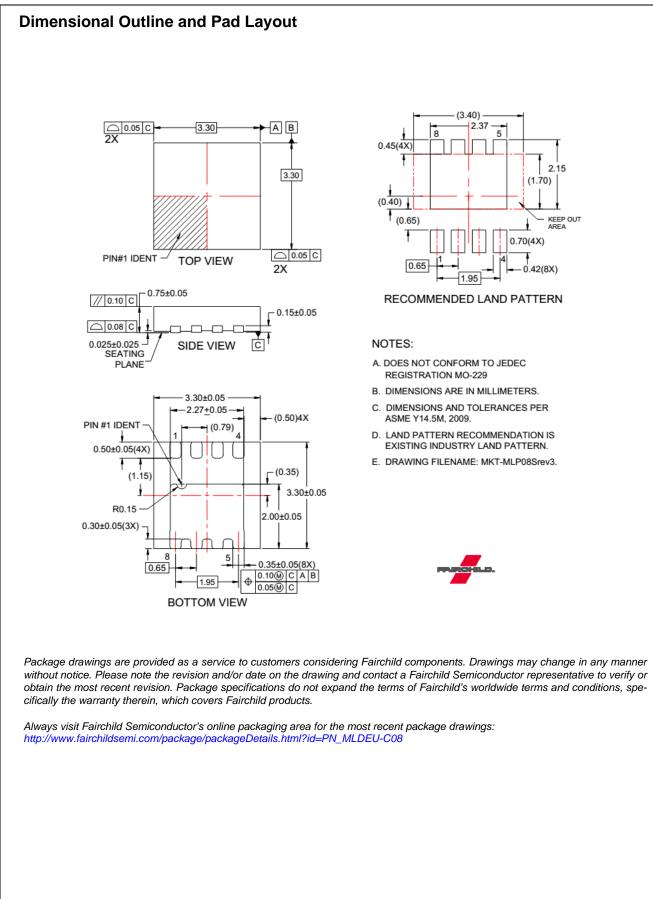


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FDMC86102L N-Channel Shielded Gate PowerTrench[®] MOSFET



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